

**Product data sheet** 

#### **1. General description**

Planar passivated Silicon Controlled Rectifier (SCR) in a SOT78 (TO-220AB) plastic package intended for use in applications requiring high bidirectional blocking voltage capability, high current inrush capability and high thermal cycling performance.

#### 2. Features and benefits

- High junction operating temperature capability (T<sub>i(max)</sub> = 150 °C)
- High thermal cycling performance
- · Planar passivated for voltage ruggedness and reliability
- High voltage capacity
- Very high current surge capability

#### **3. Applications**

- DC Motor control
- Power converter
- Lighting and temperature control
- Softstart AC motor control
- AC power control
- Solid State Relay (SSR)

#### 4. Quick reference data

Table 1. Quic	k reference data			
Symbol	Parameter	Conditions	Values	Unit
Absolute m	aximum rating			
V <sub>RRM</sub>	repetitive peak reverse voltage		1200	V
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_{mb} \le 128 \text{ °C}$ ; Fig. 1; Fig. 2; Fig. 3	31	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 10 \text{ ms}; \frac{\text{Fig. 4}}{25}; \frac{1}{25}$	250	A
		half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 8.3 \text{ ms}$	275	A
T <sub>j</sub>	junction temperature		150	°C

SCR

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	35	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	60	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 20 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.15	1.5	V
Dynamic	characteristics	·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 804 V; T <sub>j</sub> = 150 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform;	1000	-	-	V/µs

## 5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	А₽К
2	А	anode	204	G sym037
3	G	gate		Symoor
mb	A	mounting base; connected to anode		

### 6. Ordering information

Table 3. Ordering inform	nation					
Type number	Package					
	Name	Description	Version			
BT152-1200T	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78			

### 7. Marking

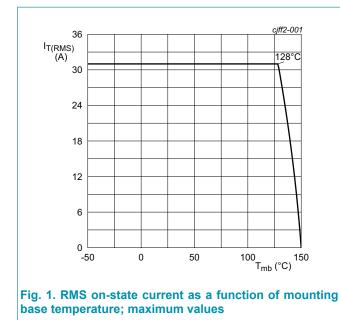
Table 4. Marking codes							
	Type number	Marking codes					
	BT152-1200T	BT152-1200T					

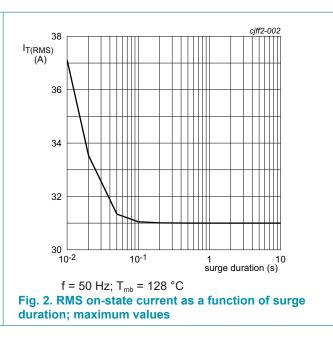
### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

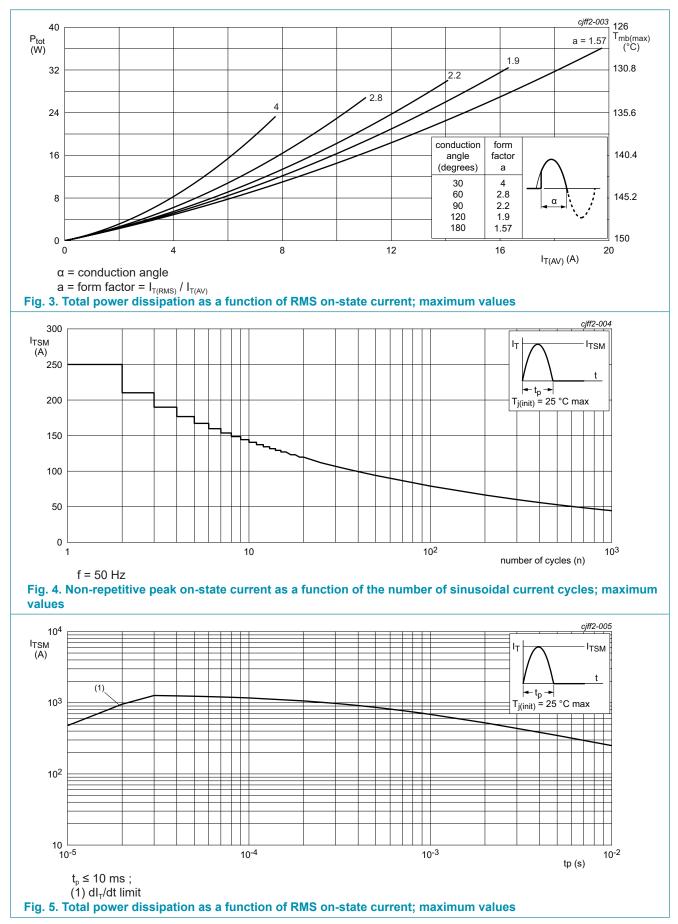
Symbol	Parameter	Conditions	Values	Unit
V <sub>drm</sub>	repetitive peak off-state voltage		1200	V
V <sub>RRM</sub>	repetitive peak reverse voltage		1200	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; $T_{mb} \le 128 \text{ °C}$ ;	20	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 128 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	31	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 10 ms; Fig. 4; Fig. 5	250	A
		half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 8.3 ms	275	A
l <sup>2</sup> t	l <sup>2</sup> t for fusing	t <sub>p</sub> = 10ms; sine wave	312.5	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 60mA	150	A/µs
I <sub>GM</sub>	peak gate current		5	A
$V_{\text{GM}}$	peak gate voltage		5	V
P <sub>GM</sub>	peak gate power		20	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	0.5	W
T <sub>stg</sub>	storage temperature		-40 to 150	°C
Tj	junction temperature		150	°C





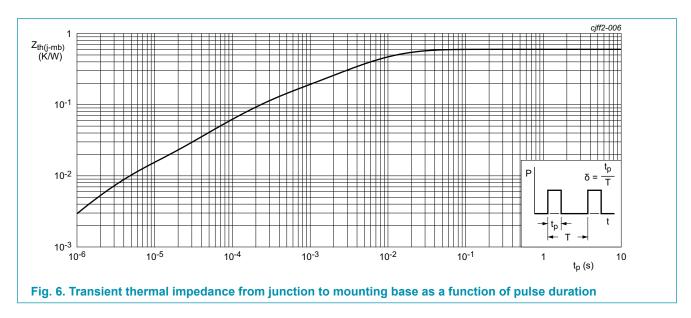
# BT152-1200T

SCR



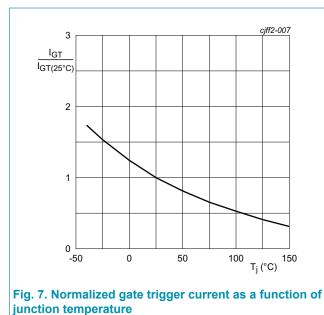
### 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	0.6	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W



### **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	racteristics			.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	Indx	Unit
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>i</sub> = 25 °C; <u>Fig. 7</u>	-	-	35	mA
I <sub>L</sub>	latching current	$V_{\rm D}$ = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 8	-	-	80	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	 -	-	60	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 20 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.15	1.5	V
V <sub>gt</sub>	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		V <sub>D</sub> = 1200 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 150 °C; Fig. 11	0.25	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 1200 V; T <sub>j</sub> = 150 °C	-	-	2	mA
I <sub>R</sub>	reverse current	V <sub>D</sub> = 1200 V; T <sub>j</sub> = 150 °C	-	-	2	mA
Dynamic o	haracteristics	· · · · · · · · · · · · · · · · · · ·				_
$dV_D/dt$	rate of rise of off-state voltage	$V_{DM}$ = 804 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform	1000	-	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM}$ = 20 A; V <sub>D</sub> = 800 V; I <sub>G</sub> = 100 mA; (dI <sub>G</sub> /dt) <sub>M</sub> = 5 A/µs; T <sub>j</sub> = 25 °C		2	-	μs
t <sub>q</sub>	commutated turn-off time			70	-	μs



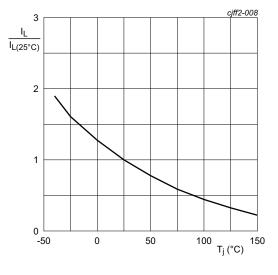
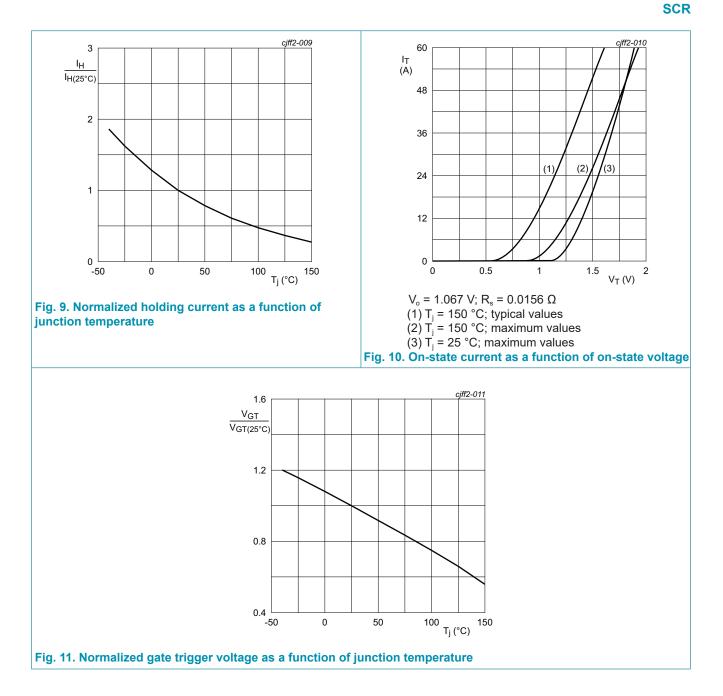


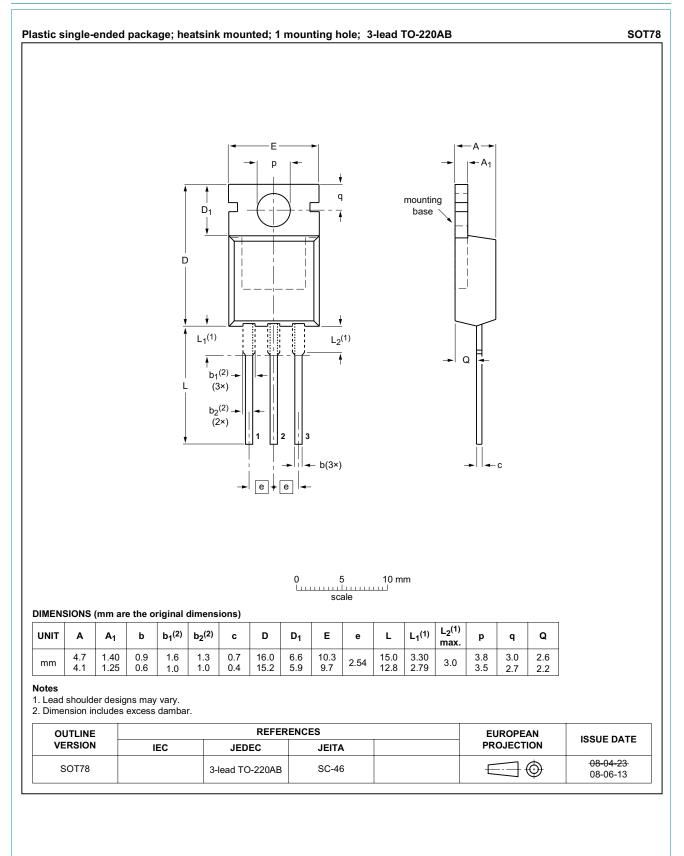
Fig. 8. Normalized latching current as a function of junction temperature

#### **WeEn Semiconductors**

BT152-1200T



#### **11. Package outline**



### 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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#### 13. Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Marking	3
8. Limiting values	3
9. Thermal characteristics	5
10. Characteristics	6
11. Package outline	8
12. Legal information	9
13. Contents	11

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